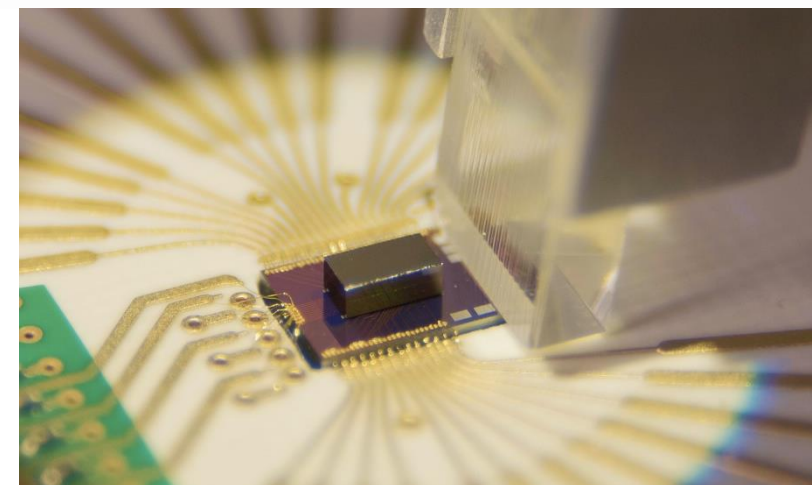


FROM RESEARCH TO INDUSTRY

cea tech



## FACE-TO-FACE INTEGRATION OF AN ELECTRO-OPTICAL LINK WITH CMOS DRIVERS AND THERMAL CONTROL

D43D Workshop – Leti Innovation Days 2018 | Yvain Thonnart



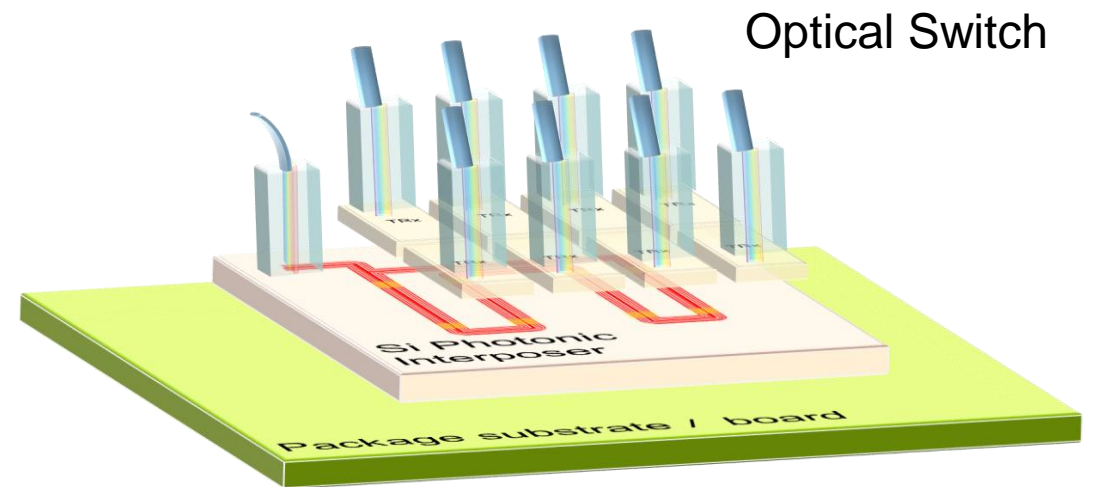
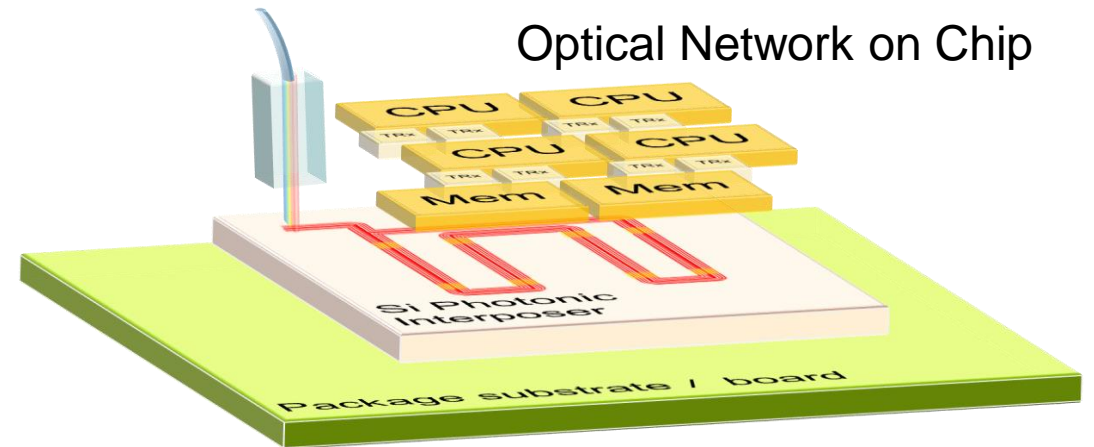
## Silicon Photonics moves forward for long distance optical wireline transceiver

- 100 / 400 Gigabit Ethernet

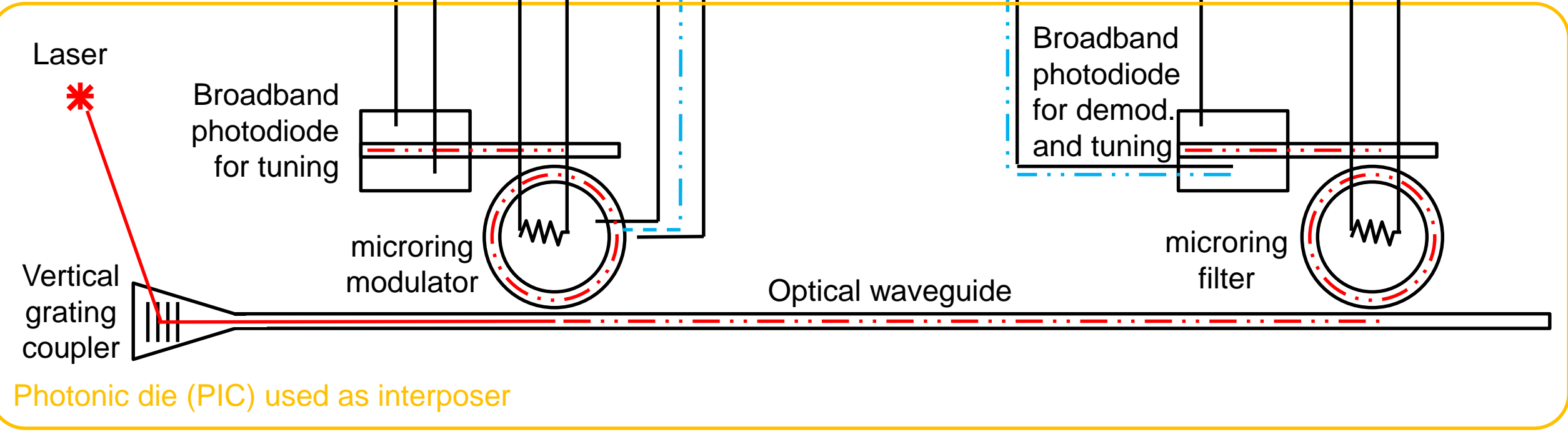
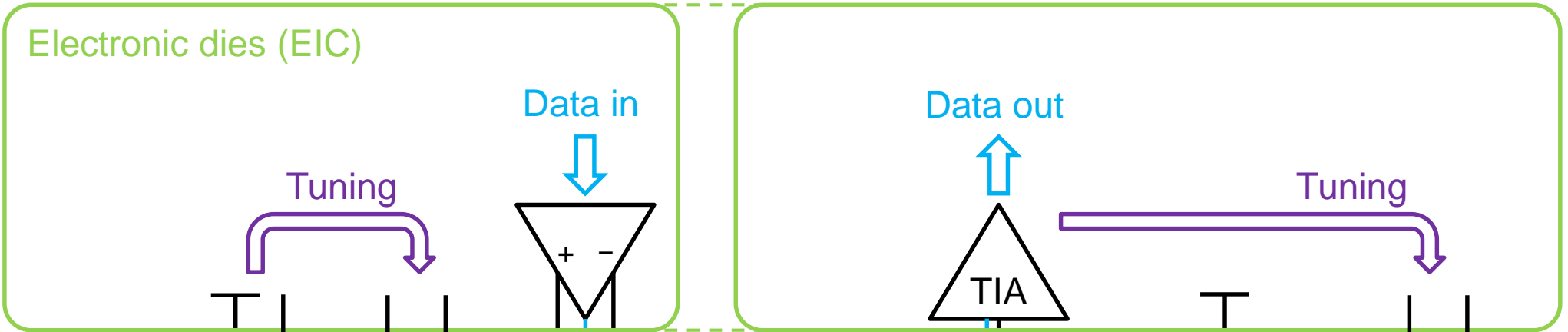
Large-scale electronics longs for low-latency low-energy dense communication

Optical short-range communication has been a long-term target for years

- Needs compact optical devices to maximize bandwidth per mm<sup>2</sup>  
→ **Microring optical resonators**



# MICRORING MODULATOR BASED LINK



Photonic die (PIC) used as interposer

## Compact optical devices

- Highly resonant: Q-factor 10,000–30,000

Any refractive index change shifts the resonant wavelength

PN or PIN diode junction can be created inside the ring for electrical control

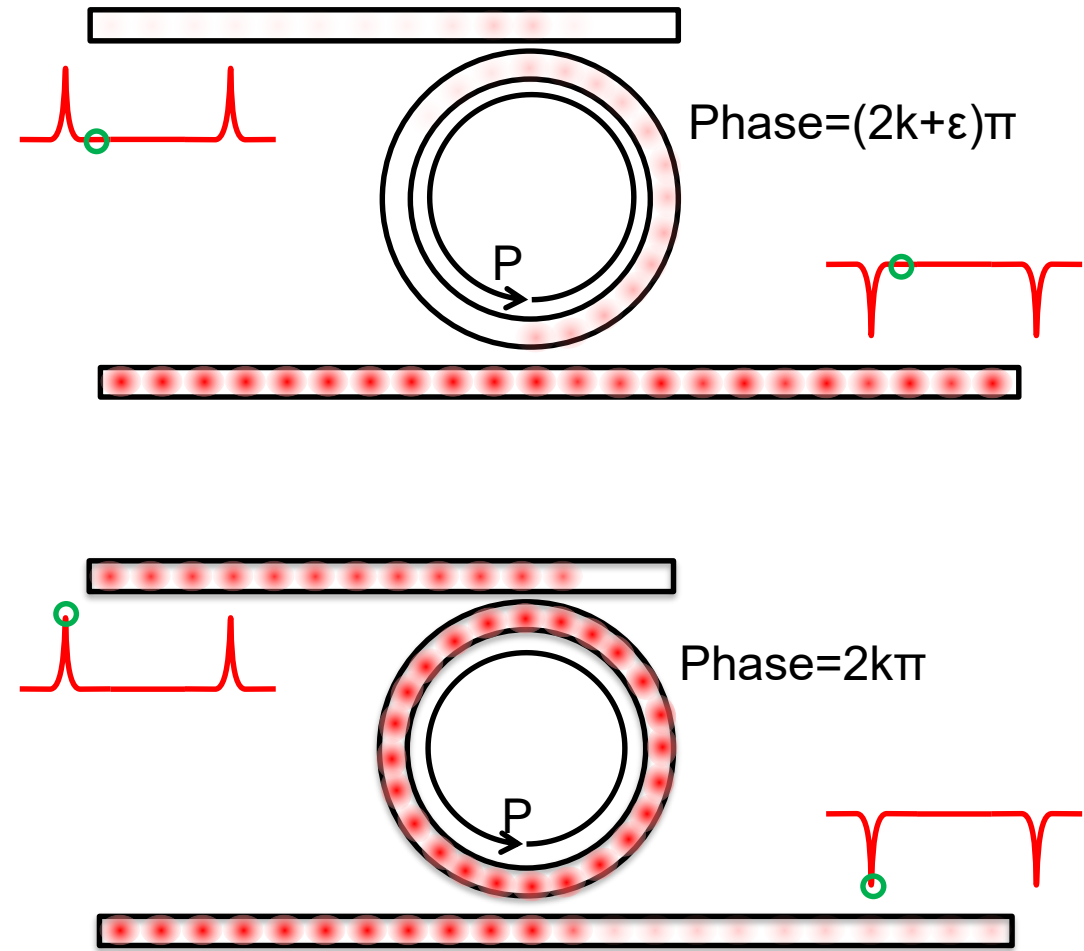
- Different uses depending on diode
  - PN rings can be used as modulators (> 10 Gbps)
  - PIN rings can be used as filters (<500 MHz) for routing and wavelength demultiplexing

**But Subject to Temperature variations**

→ Low-frequency resonance shift

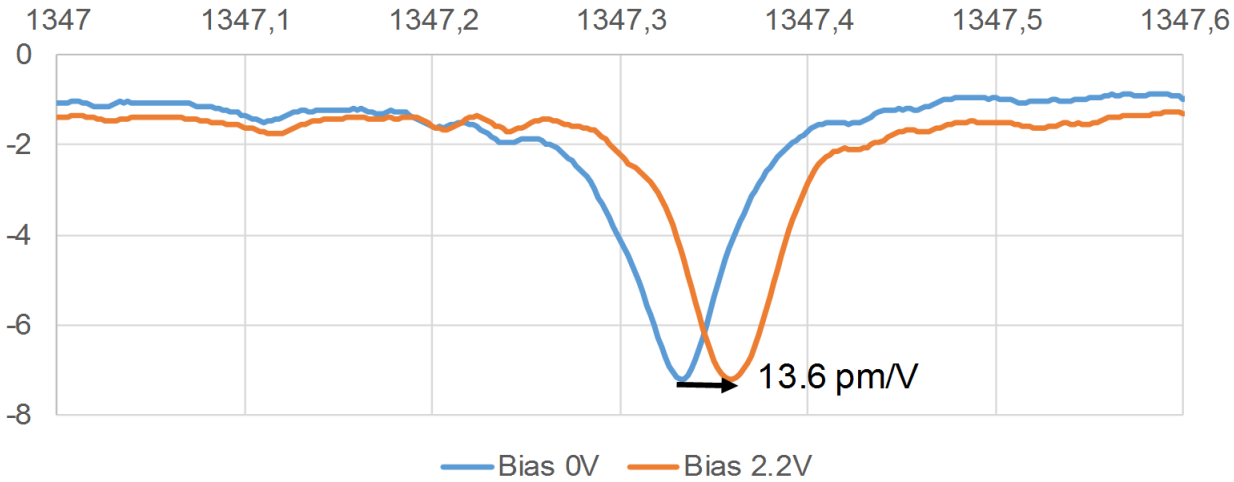
## MICRORING: OPTICAL RESONANT CAVITY

$$\lambda_{res} = \frac{P n_{eff}}{k}$$

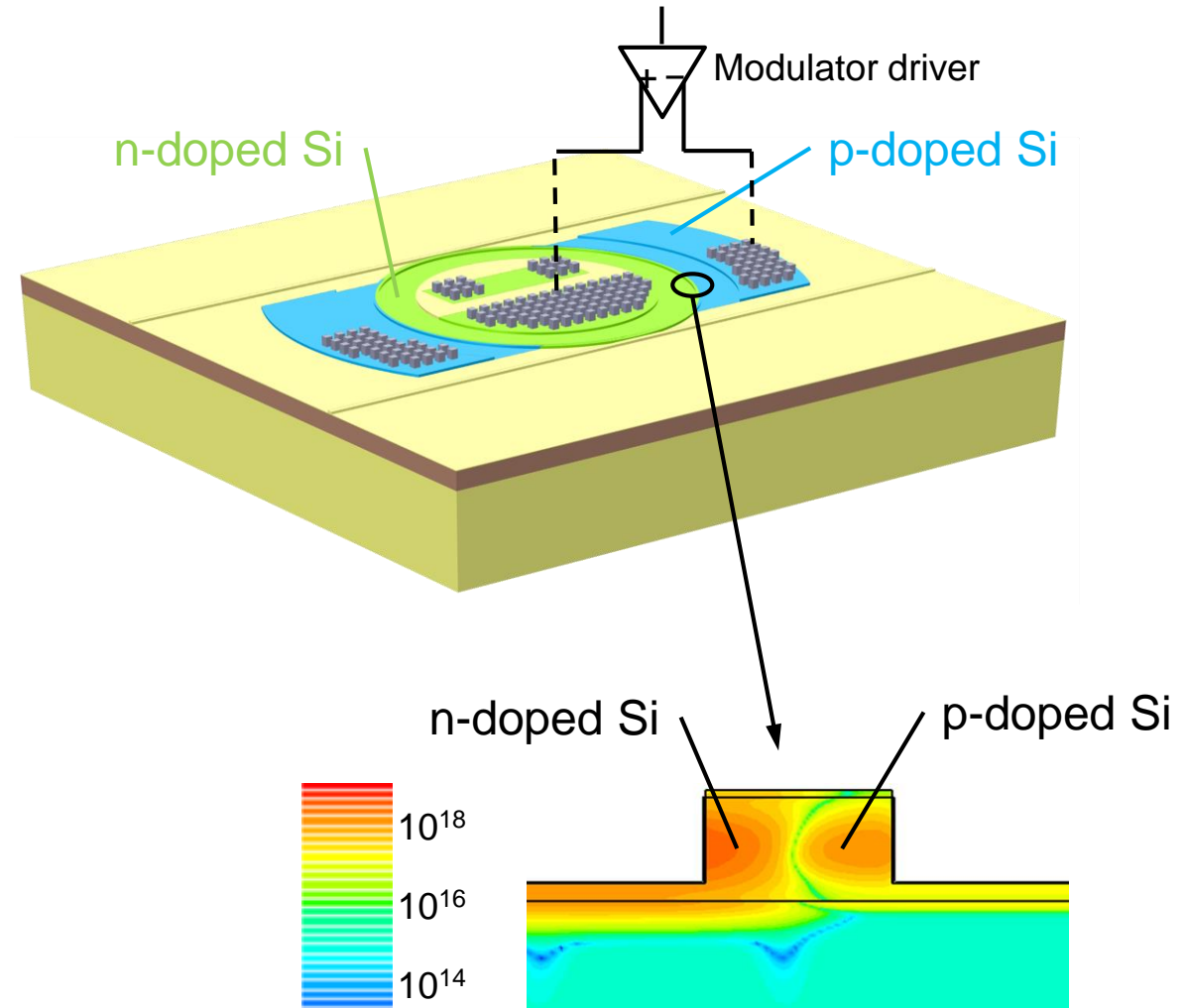
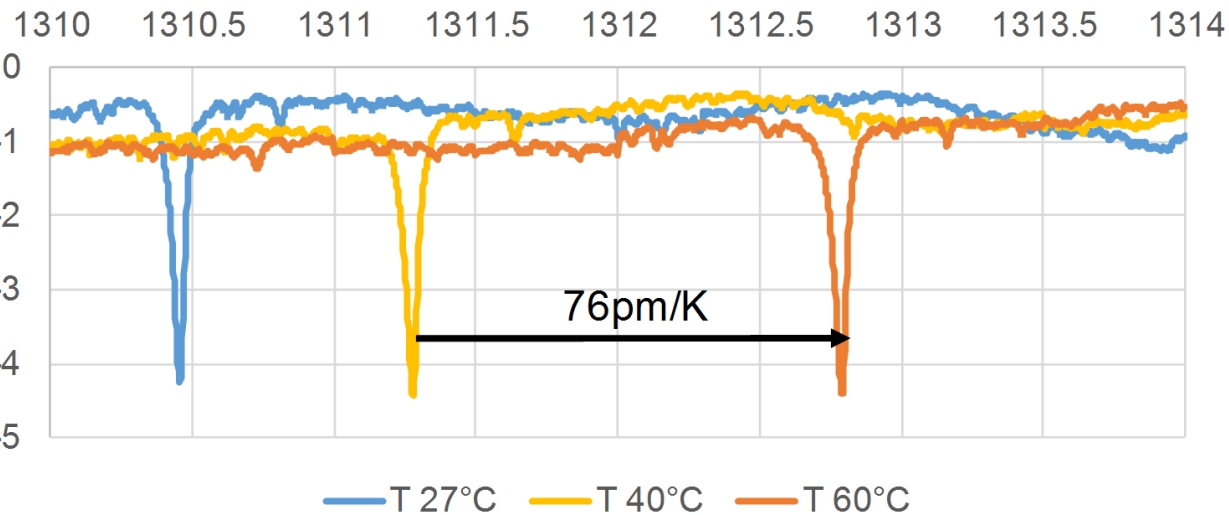


# MODULATOR PRINCIPLE, THERMAL SENSITIVITY D/DV & D/DT MEASUREMENTS

## 13.6 pm/V modulation efficiency



## 76 pm/K thermal sensitivity



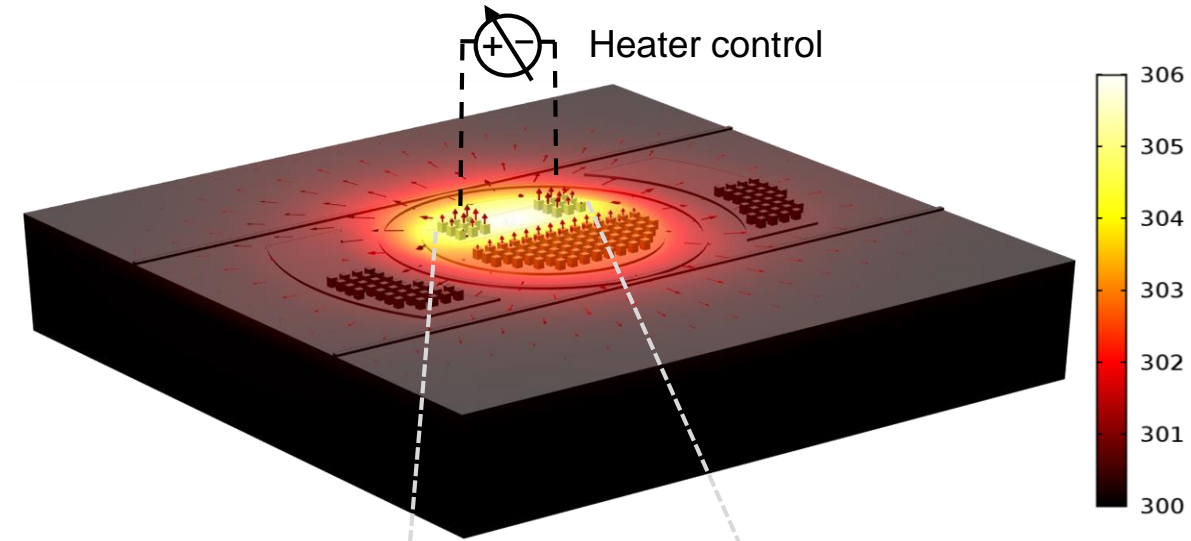
# HEATER EFFICIENCY & D/DP MEASUREMENTS

## Heating using doped Silicon

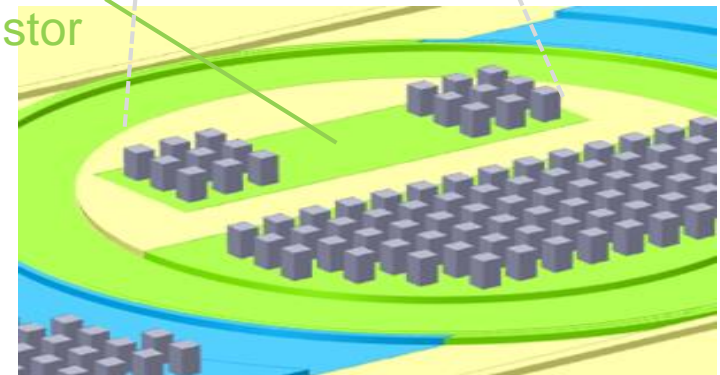
- Resistive path inside the ring

## Average ring temperature increase:

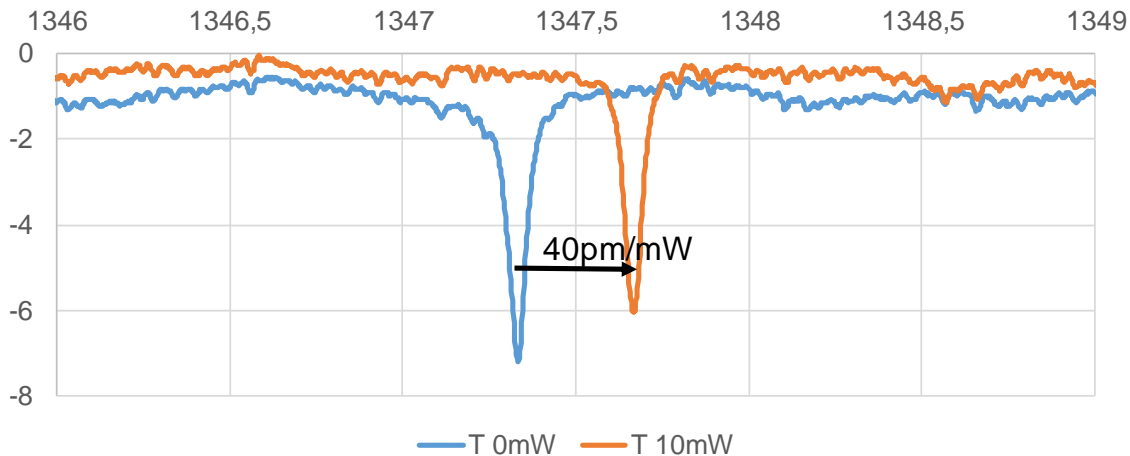
- Simulation:  $dT/dP \sim 2K/mW$
- Measurements:  $d\lambda/dP \sim 40pm/mW$



n-doped Si  
Used as resistor



Resonance shift under 10mW heating



## Ring resonant wavelength unpredictable at design time

- 1 nm thickness variation  
≈ 1 nm resonance shift

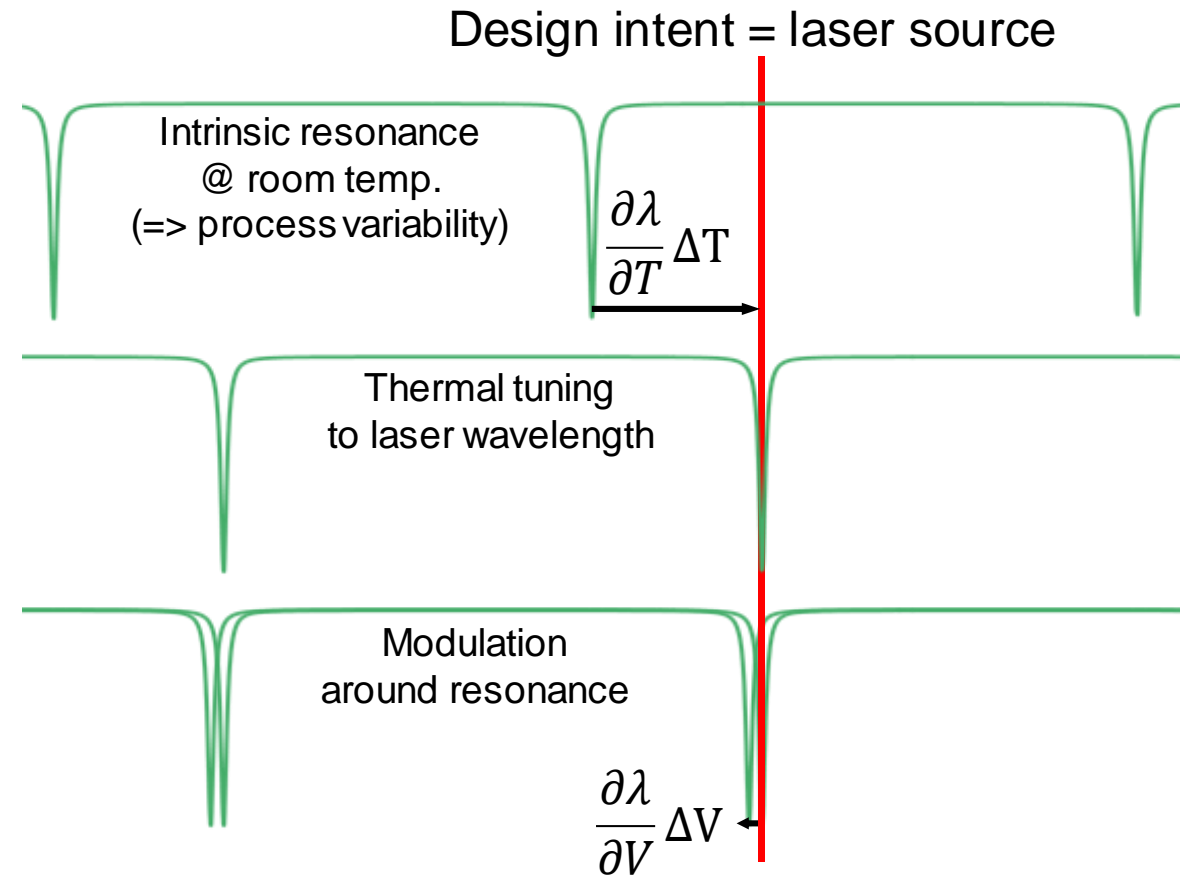
**But finesse, free-spectral-range & amplitudes are well-controlled**

## Thermal tuning is used to align ring resonance on laser source

- Low-frequency control

## Voltage is used to modulate light

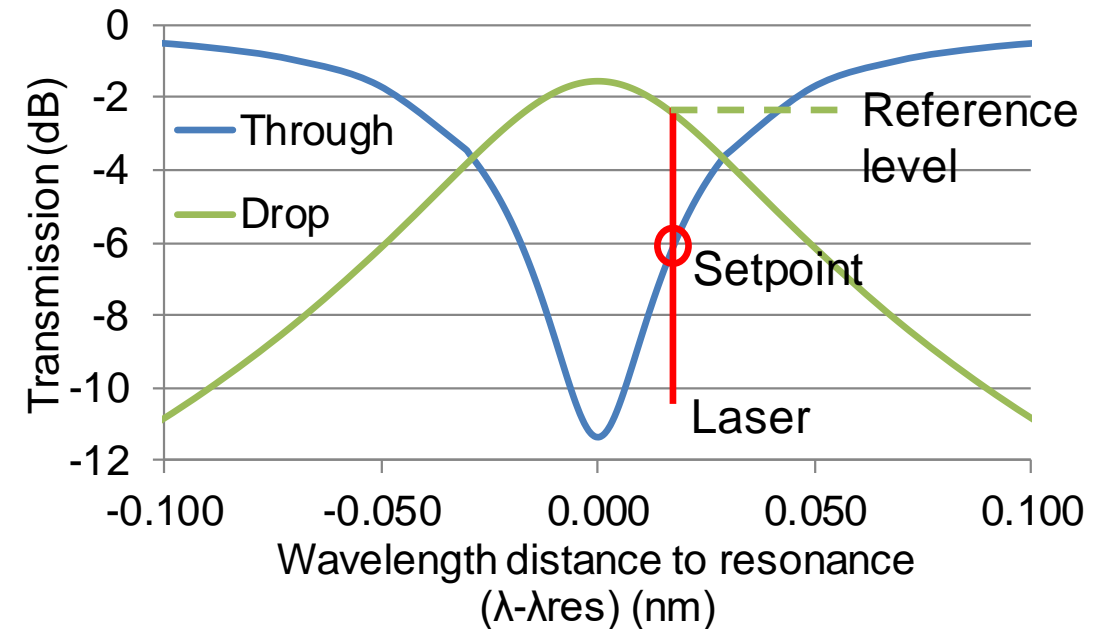
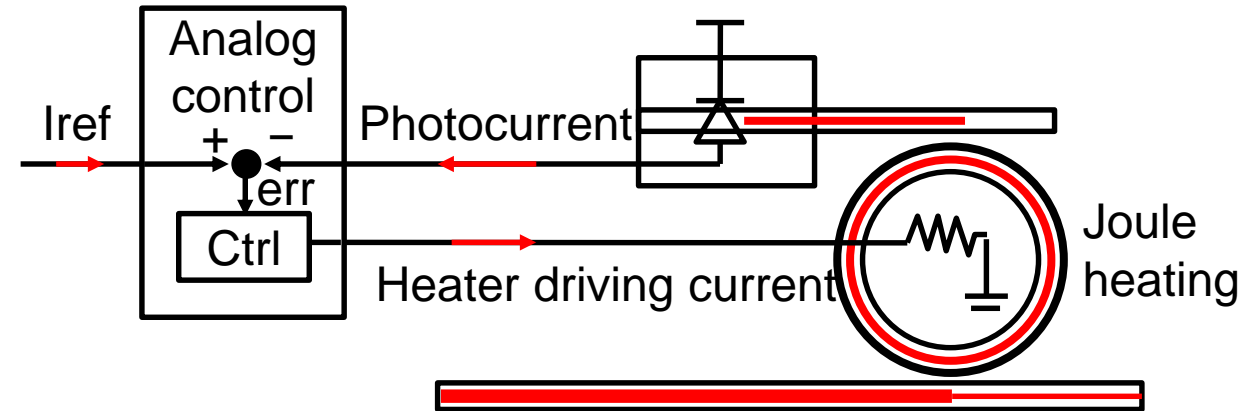
- High frequency modulation



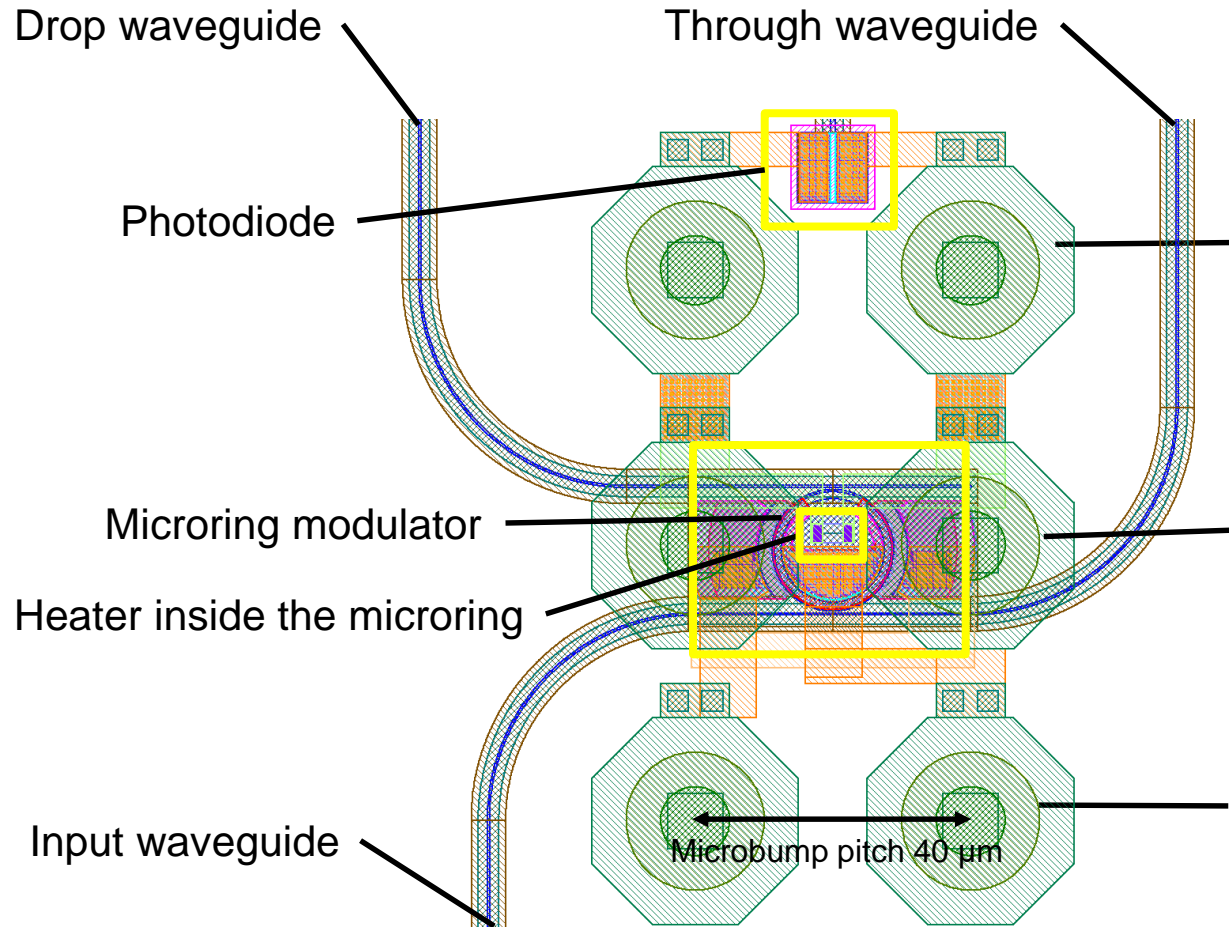
## Ring resonance can be tracked by transmission on drop port

- Setpoint on through port corresponds to a power value on drop port
- Photodiode converts this to photocurrent
- Analog control used to match photocurrent with reference
- Joule heating by resulting heater driver current

## LOCKING ON REFERENCE CURRENT LEVEL VIA USE OF DROP PORT & PHOTODIODE







- 6 microbumps per wavelength

- 3 Kinds, different constraints:

**Photodiode microbumps**

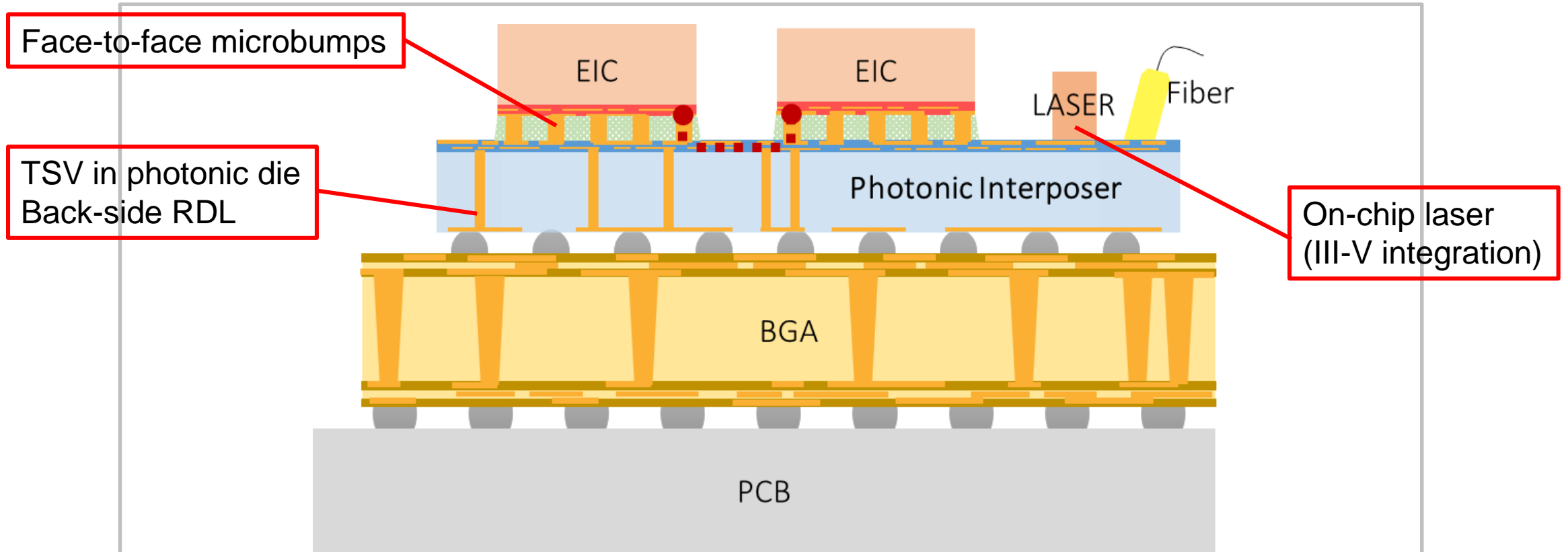
➔ Photocurrent: 10-100 $\mu$ A @ DC-10Gbps

**Heater microbumps**

➔ Joule current: 0-2mW @ DC

**Modulator microbumps**

➔ Modulation voltage: 0-2.4V @ 10Gbps



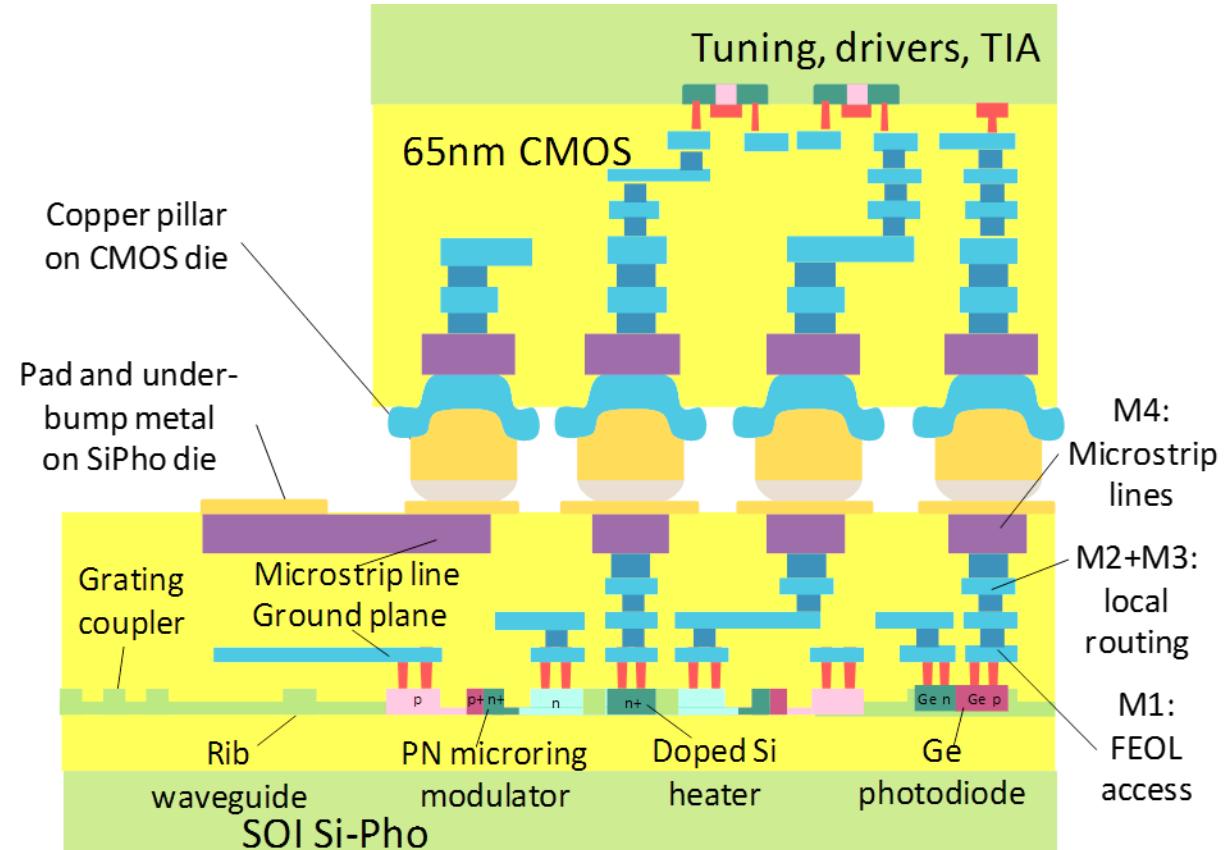
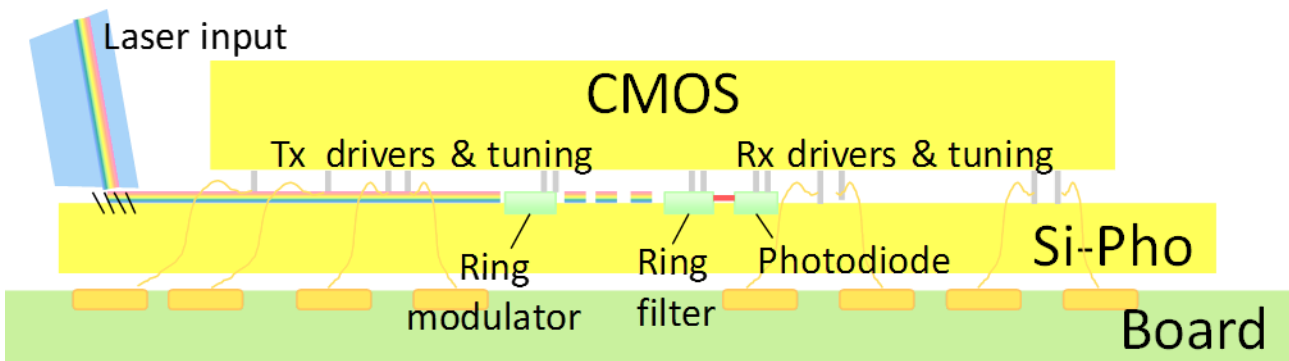
*Kevin Morot,  
Intégration et modélisation RF des interconnexions 3D pour l'interposeur photonique,  
PhD dissertation*

## Copper-pillar Face-to-face assembly

- CMOS: STMicro. 65nm LP
- Photonic: STMicro. Internal 100nm SiPho

## Wire-bonding on Photonic die

## Vertical Fiber array on grating couplers



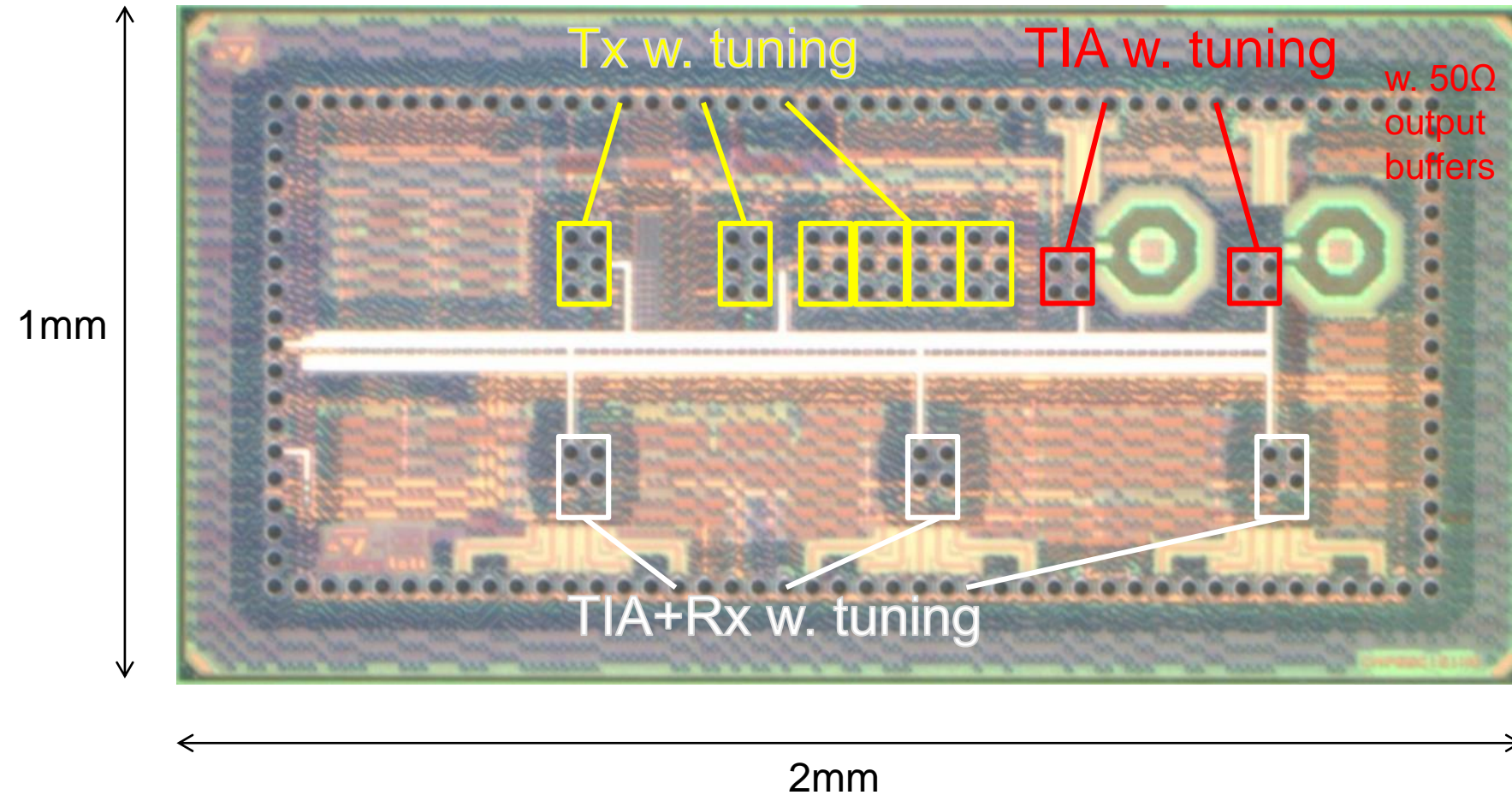
## ELECTRONIC DIE

### Functional area per $\lambda$

- Heater control
  - $40 \times 40 \mu\text{m}^2 / \lambda$
  - $40 \times 40 \mu\text{m}^2 / \text{WDM}$
- Tx Driver
  - $40 \times 40 \mu\text{m}^2$
- Rx Driver
  - $80 \times 40 \mu\text{m}^2$

### Dominated by 6 Cu-Pillar area

- Pitch  $40 \mu\text{m}$
- 2 for Modulator
- 2 for Photodiode
- 2 for Heater

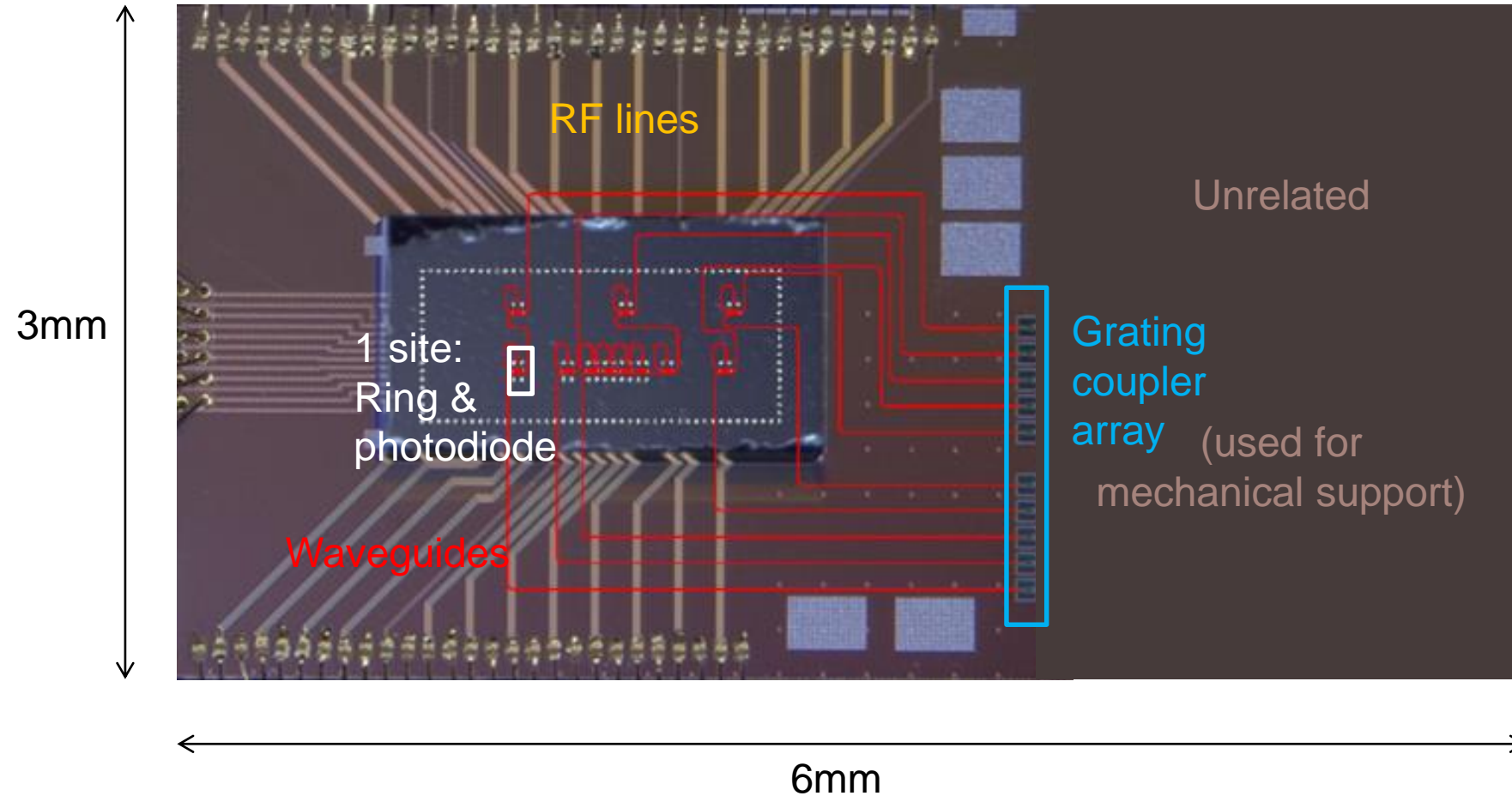


Functional area per  $\lambda$

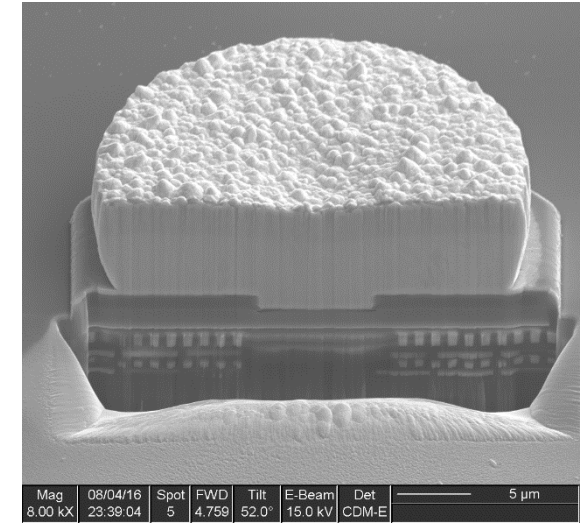
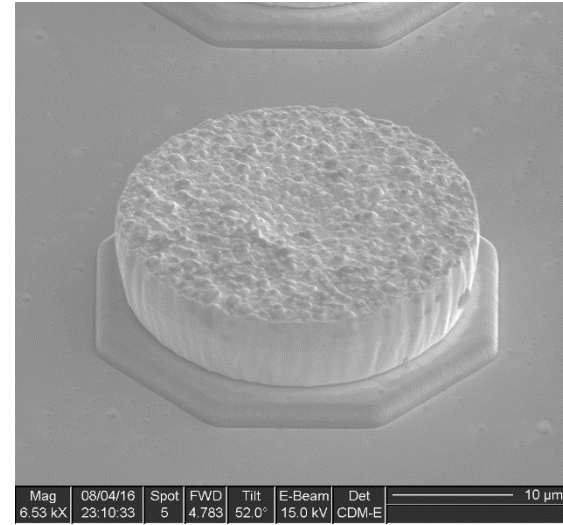
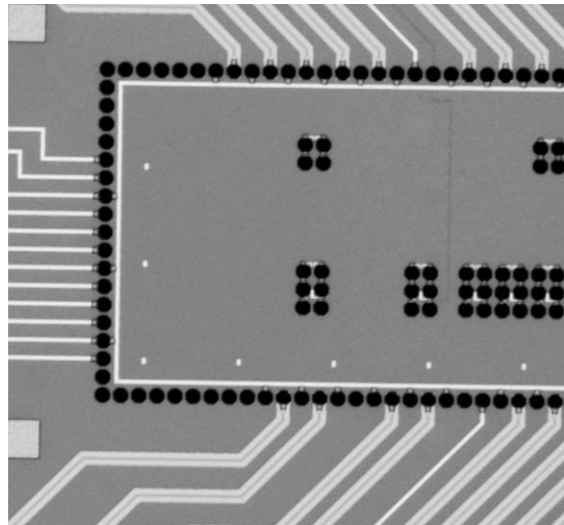
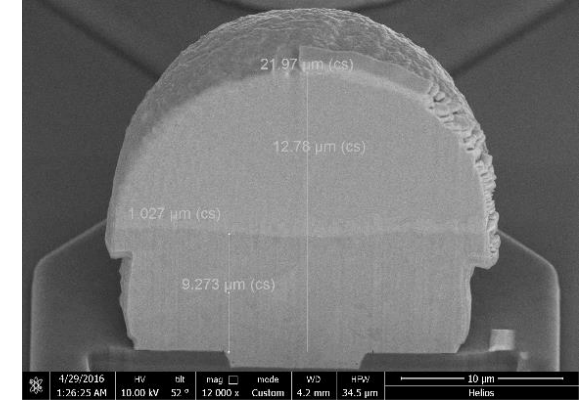
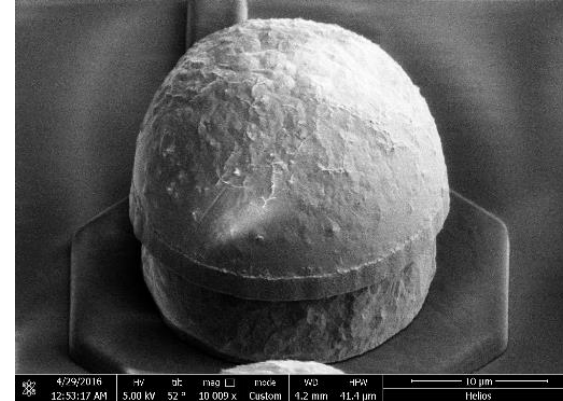
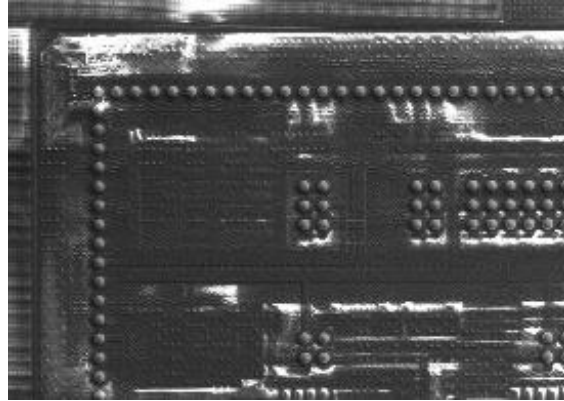
- 1 ring + 1 photodiode
- $120 \times 80 \mu\text{m}^2 / \lambda$

Dominated by 6 Cu-Pillar area

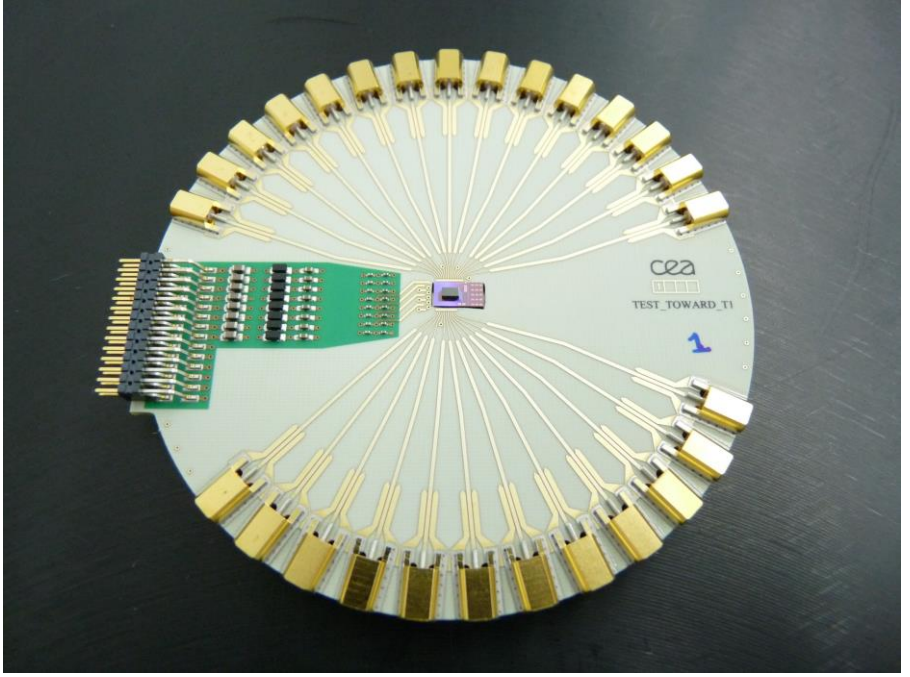
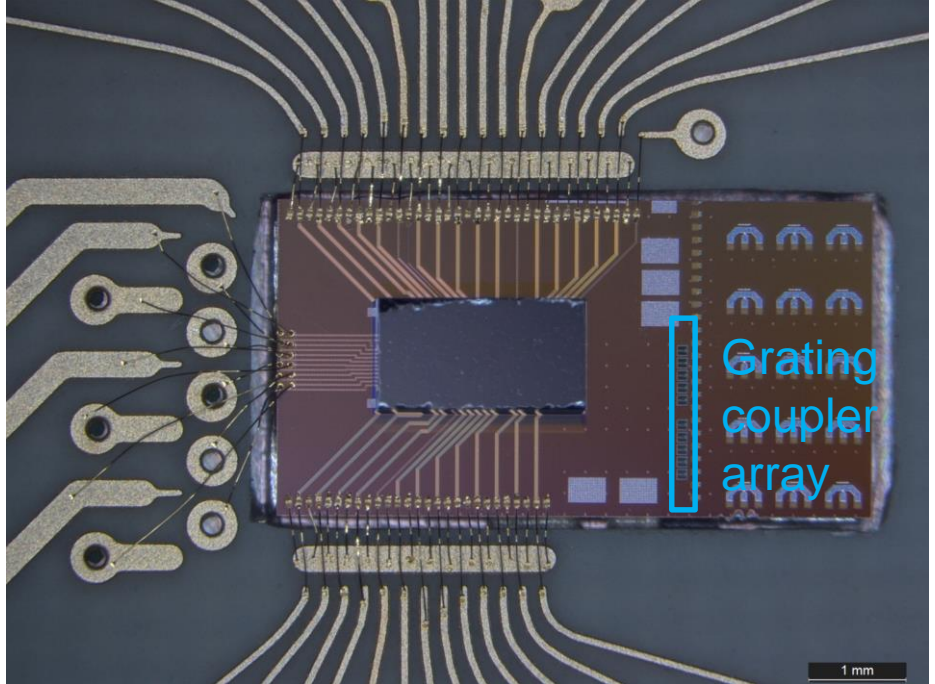
- Pitch  $40 \mu\text{m}$
- 2 for Modulator
- 2 for Photodiode
- 2 for Heater



# FACE-TO-FACE MICROBUMP ASSEMBLY

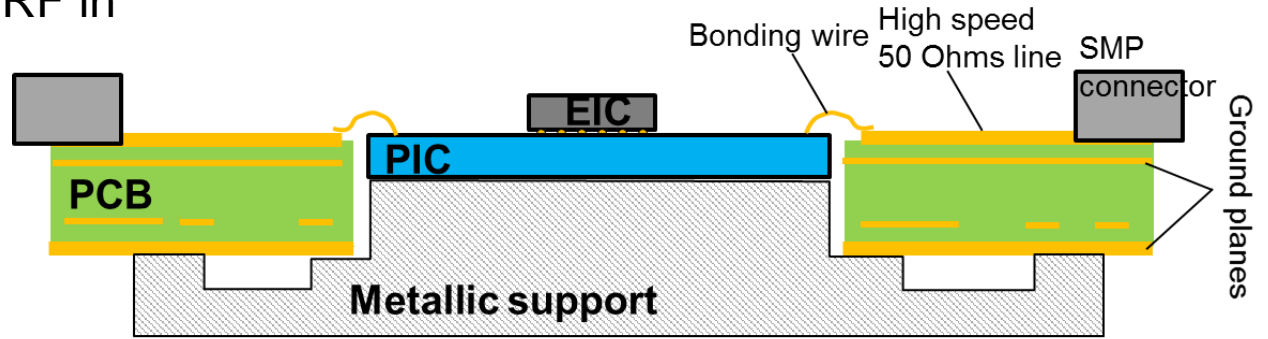


RF out

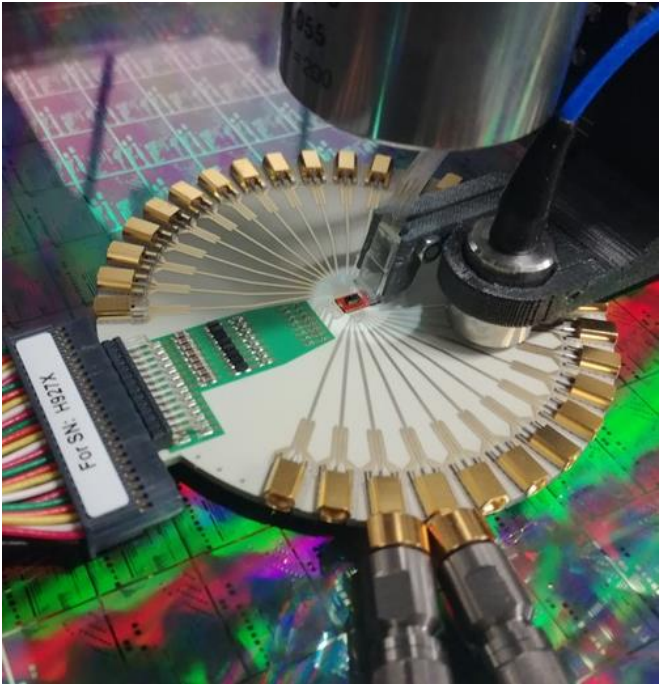
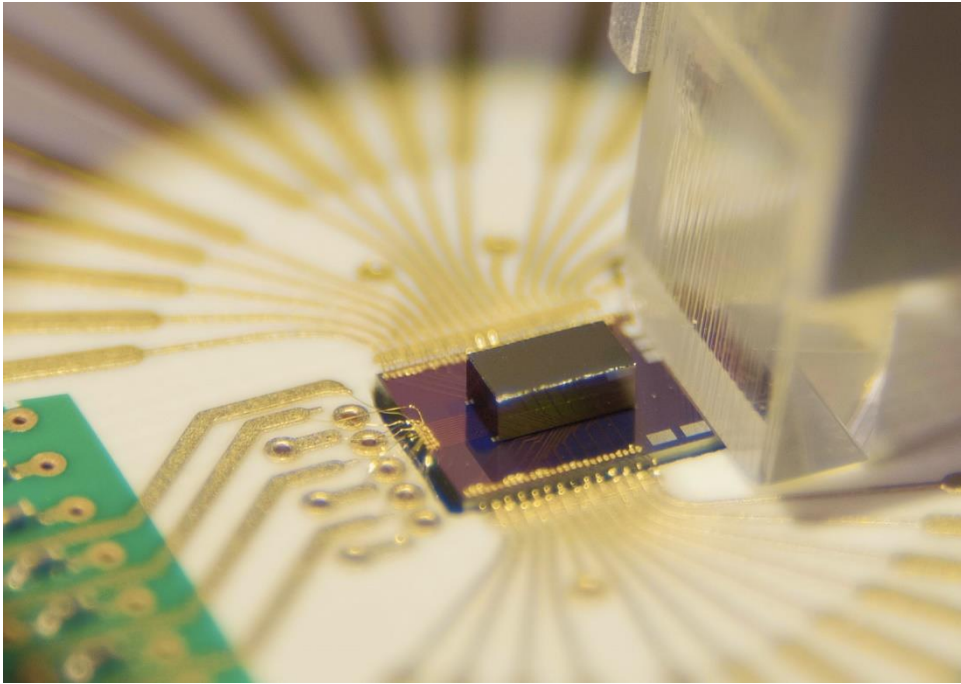
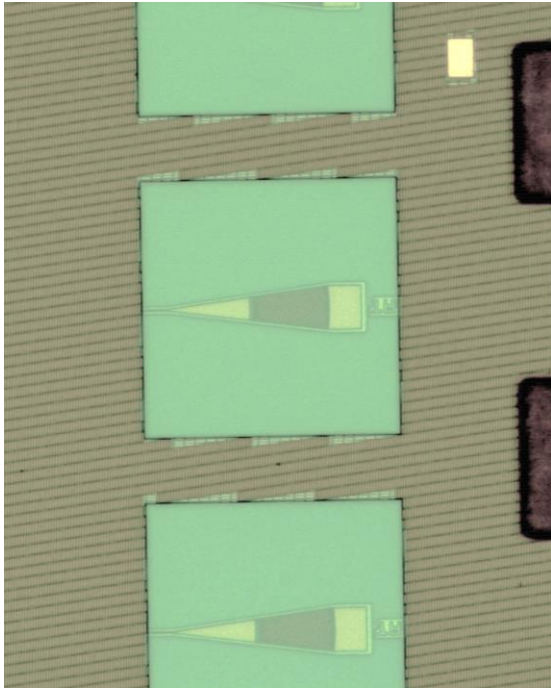


DC supplies & config.

RF in

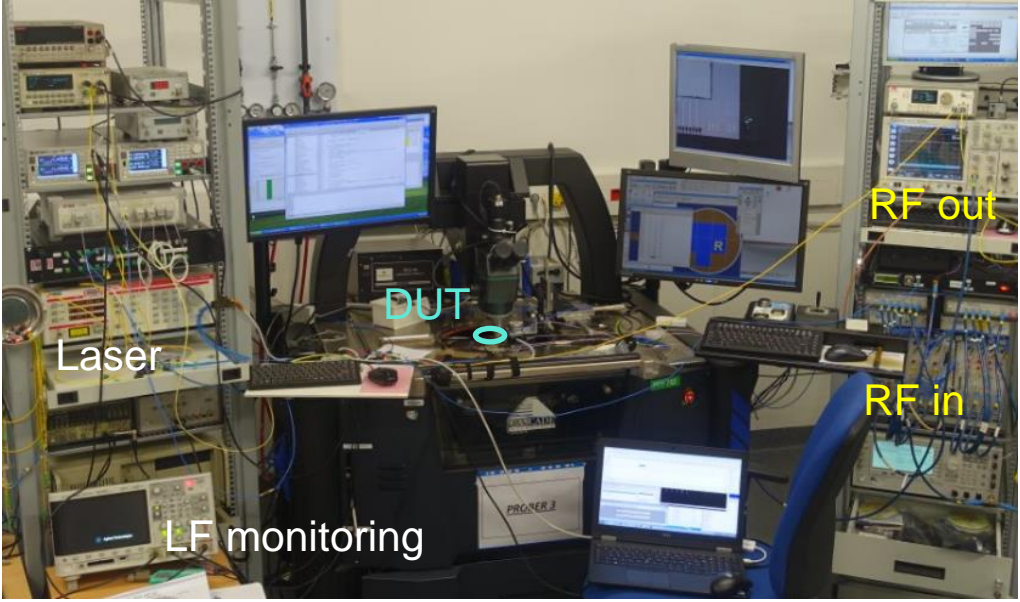
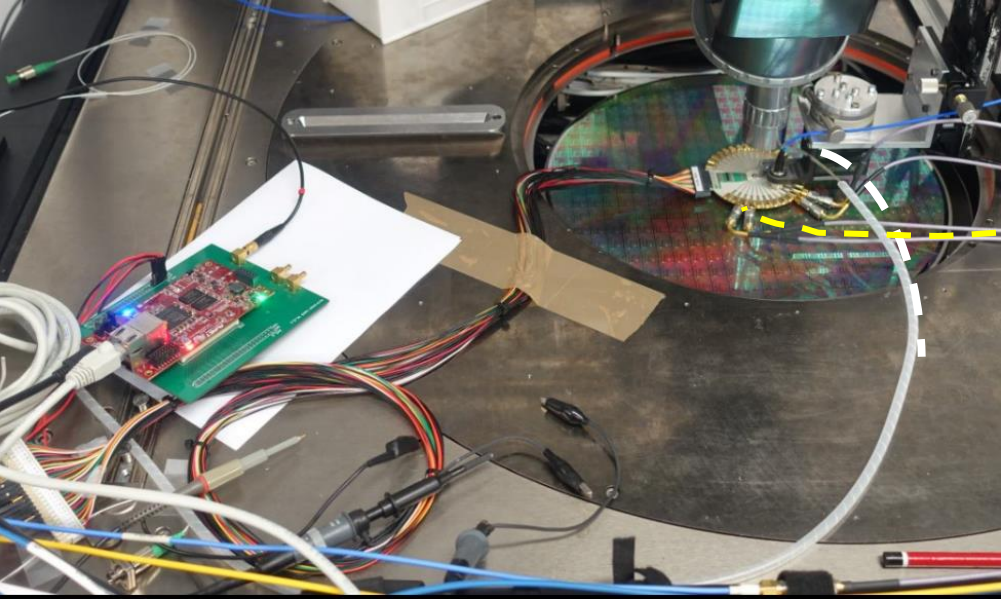
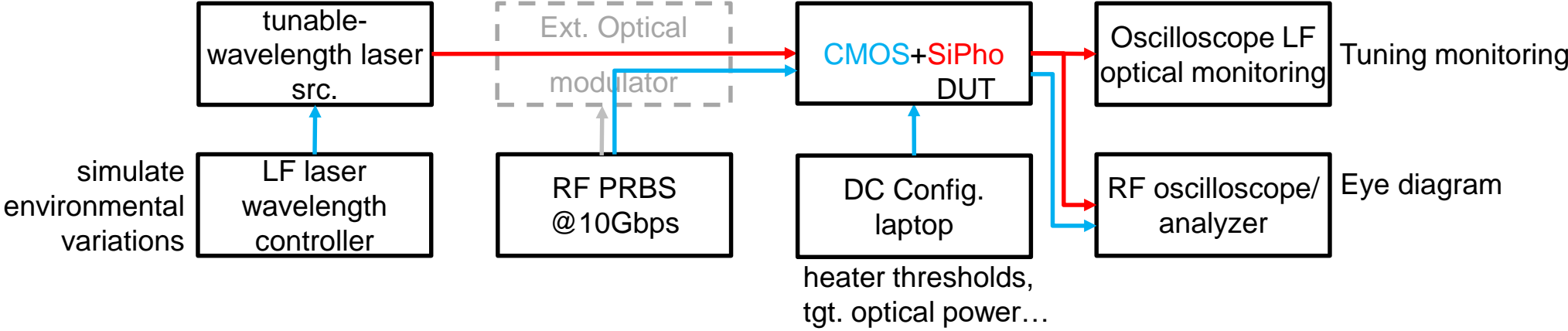


# FIBER POSITIONING ON GRATING COUPLERS



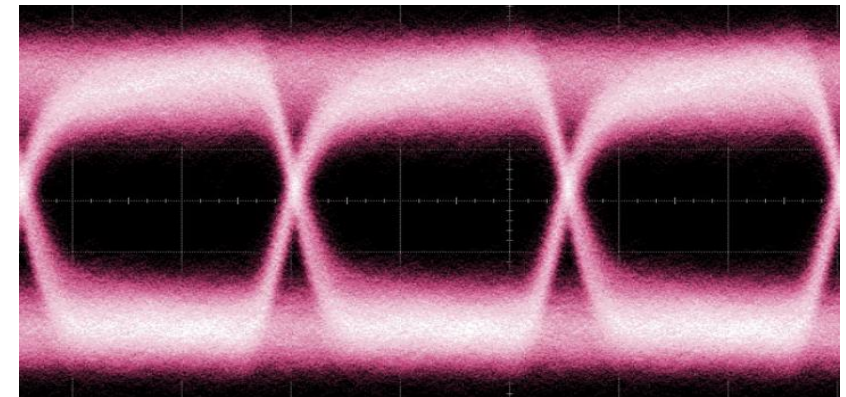
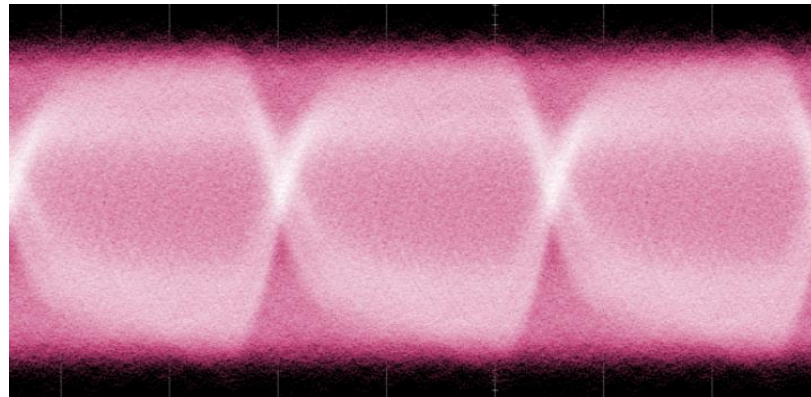
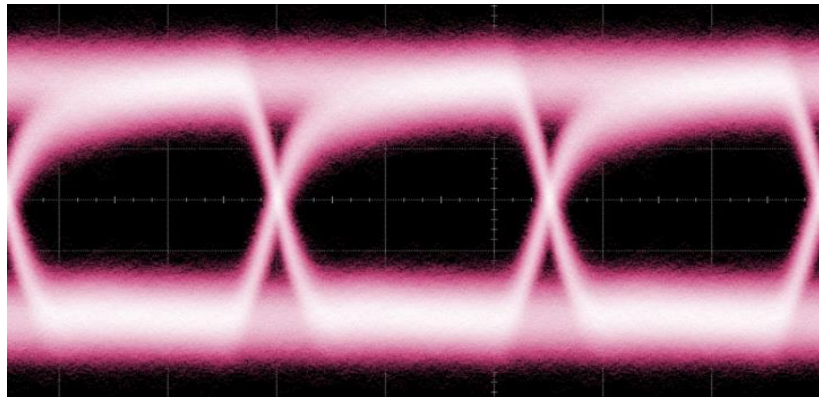
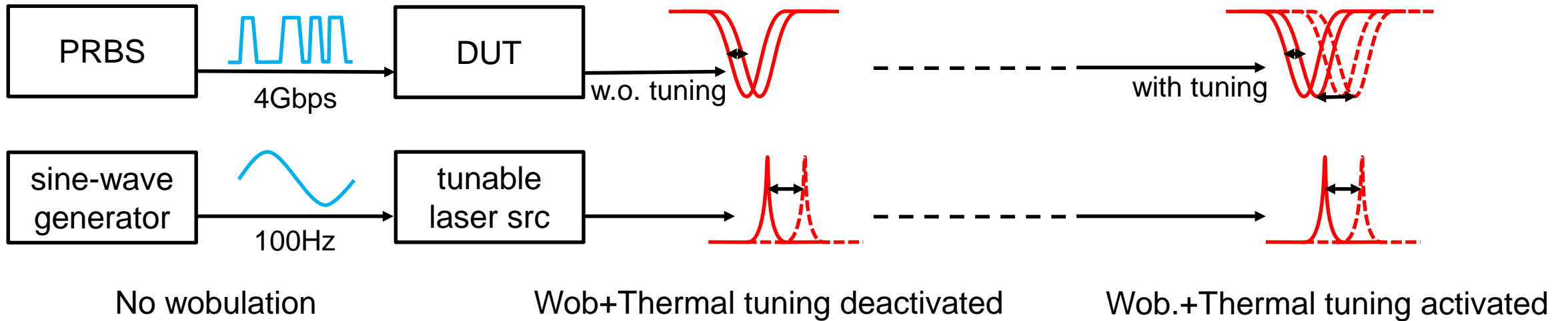


# EXPERIMENTAL SETUP



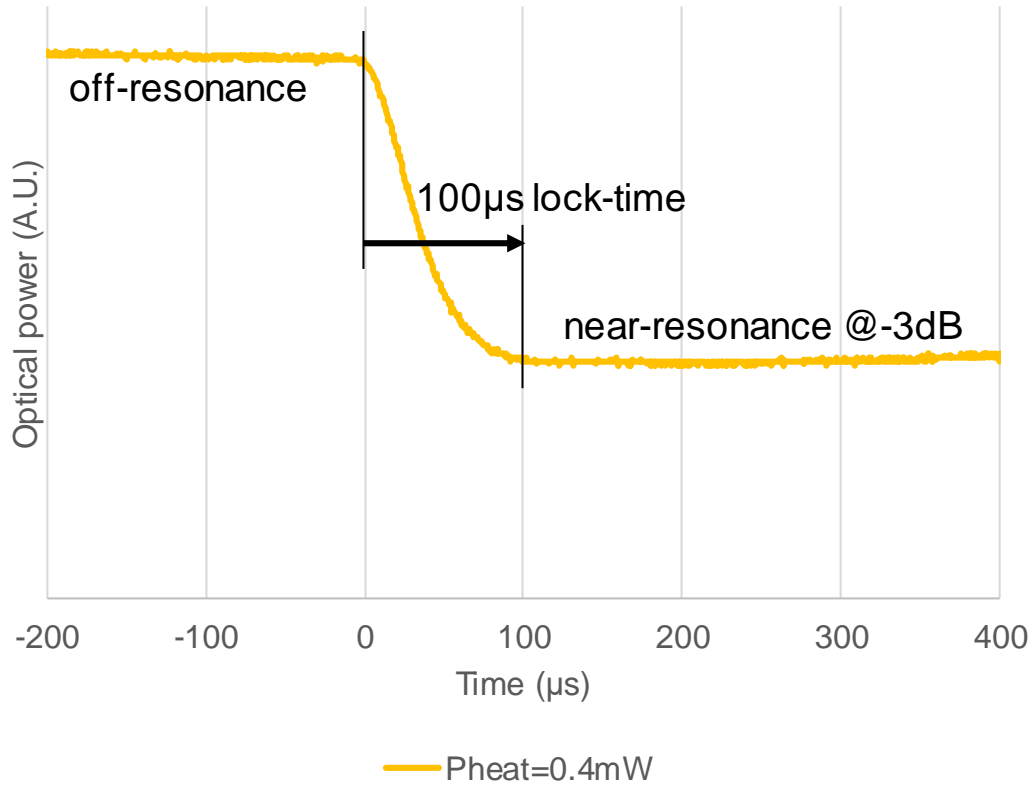
# CIRCUIT OBJECTIVE: PRESERVE COMMUNICATION DESPITE ENVIRONMENTAL PERTURBATION

Experiment: 4Gbps modulation under laser wavelength wobulation  $30\text{pm}_{pp}$  at 100Hz  
 → Simulate thermal effect of workload changes on package (~1-10ms time constant)

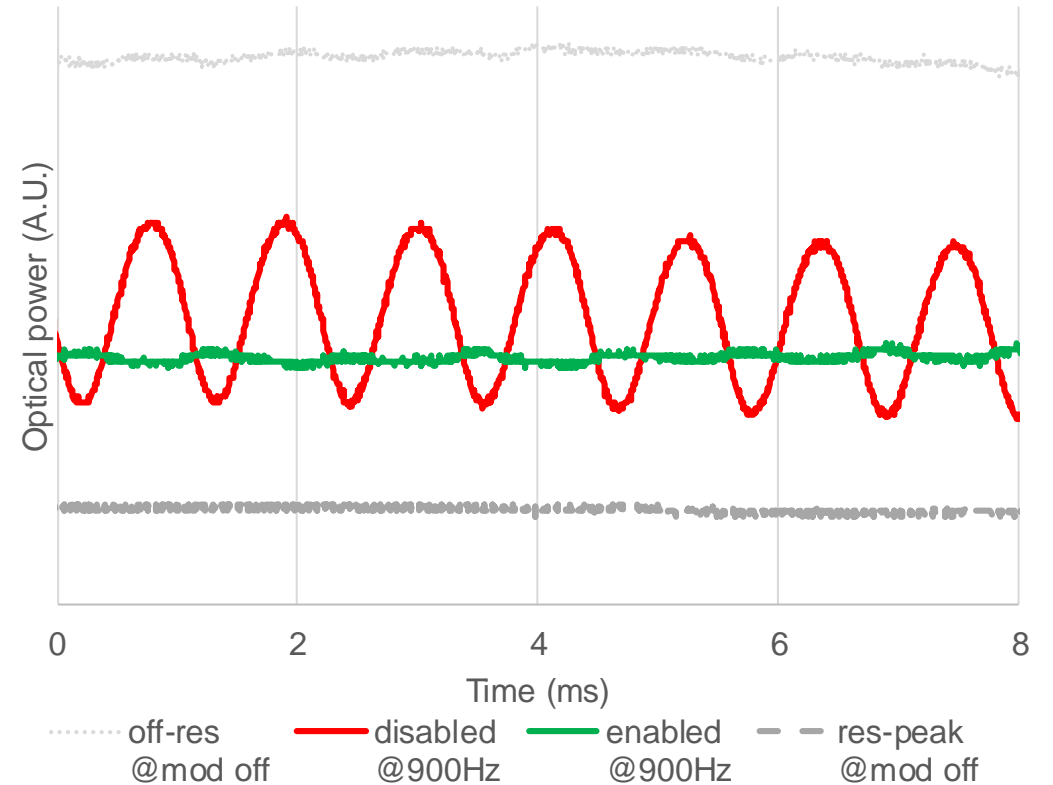


# THERMAL LOCKING AND STABILITY

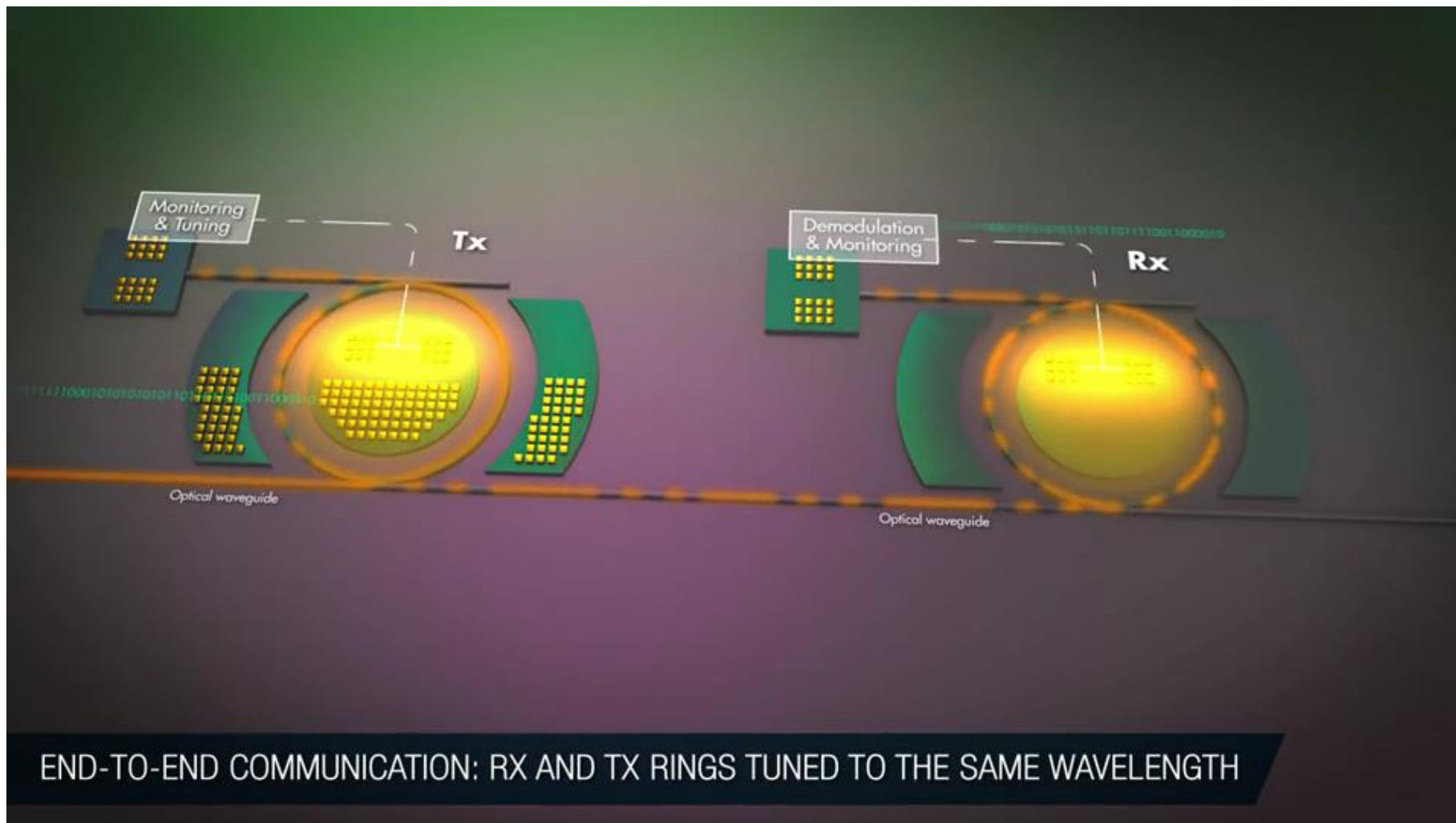
Wavelength locking on reference level on thermal control activation / remapping



Thermal control stability under 30pm<sub>pp</sub> wavelength wobulation

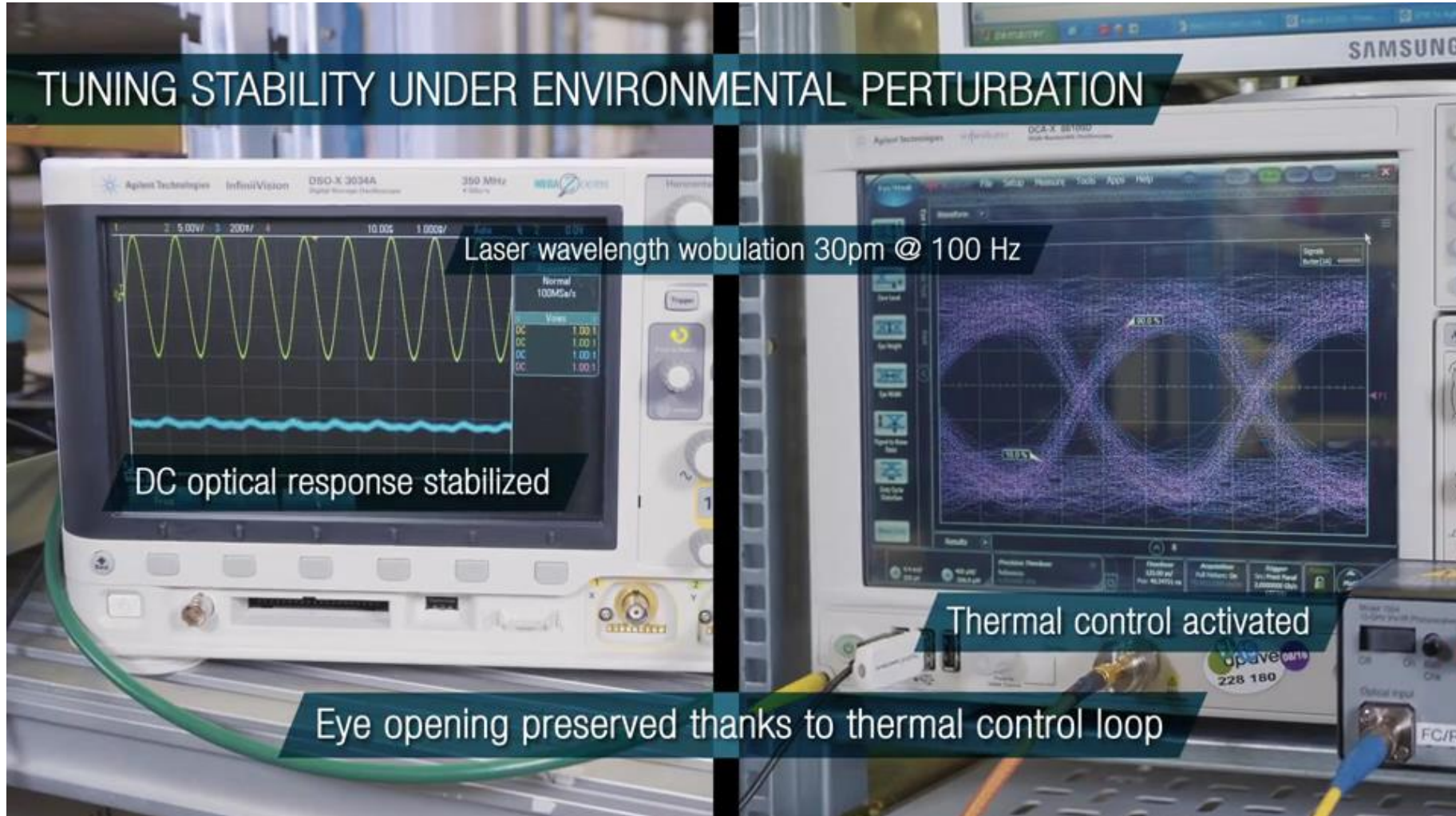


# ROBUST ELECTRO-OPTICAL LINK OPERATION UNDER PERTURBATION





# ROBUST ELECTRO-OPTICAL LINK OPERATION UNDER PERTURBATION

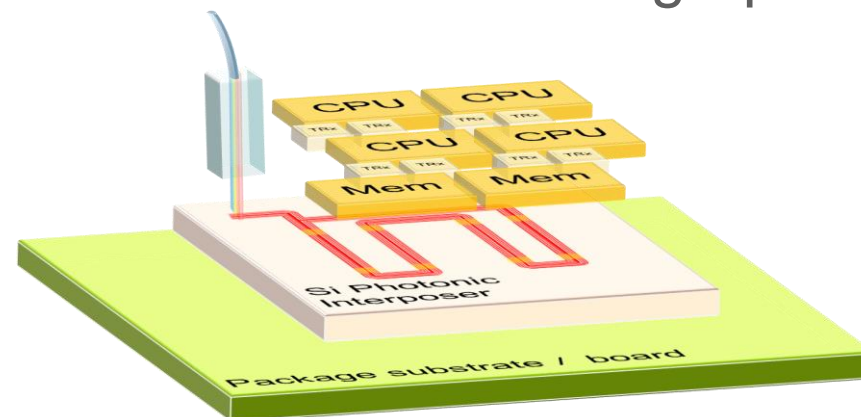


## 3D-stacked CMOS / SiPho for short-range optical communication

- 10Gbps transceiver chip presented at ISSCC'18
- Wavelength locking achieved in 120 $\mu$ s
- Stability maintained under 900Hz environmental fluctuation
- Total CMOS footprint 0.01mm<sup>2</sup> / microring  $\rightarrow$  up to 1Tbps/mm<sup>2</sup>

## Perspective

- all-to-all optical network on chip architecture on interposer for high-density optical communication in high-performance computing systems



# Thank you!

With special acknowledgments to all contributors & collaborators:

Mounir Zid, José Luis Gonzalez Jimenez, Guillaume Waltener, Robert Polster, Olivier Dubray, Florent Lepin, Stéphane Bernabé, Sylvie Menezo, Gabriel Parès, Olivier Castany, Laura Boutafa, Philippe Grosse, Benoît Charbonnier, Alexandre Siligaris, Sébastien Martin, Frédéric Hameau, Jérôme Prouvée, Christian Bernard, Eric Guthmuller, Marie-Sophie Redon, Sylvain Choisnet, Pascal Vivet, Benjamin Caillat, Edouard Grellier, Maryse Fournier, Vincent Reboud, Benjamin Blampey

Eric Cassan, Charles Baudot, Sébastien Le Beux, Jiang Xu, Sébastien Rumley, Ayse Coskun & their respective groups

**leti**

Centre de Grenoble  
17 rue des Martyrs  
38054 Grenoble Cedex

**list**

Centre de Saclay  
Nano-Innov PC 172  
91191 Gif sur Yvette Cedex

